

L-Band, GaN/SiC, RF Power Transistor

960-1220 MHz | 320 W typ | 60% Efficiency typ | 18dB Gain typ | 50 V | Link 16

IGN0912L250M and IGN0912L250MS are high power GaN-on-SiC RF power transistors that have been designed to suit the needs of IFF/SSR avionics systems, military tactical data links, and TACAN/DME systems. They operate over the full instantaneous bandwidth of 960-1220MHz. Under Link 16 [444x (7µs on, 6µs off), 22.7% Long Term Duty Cycle] pulse conditions they supply a minimum of 250 W of peak output power, with typically 17 dB of associated gain and 50% efficiency. They operate from a 50 V supply voltage. For optimal thermal efficiency, the transistors are housed in a metal-based package with an epoxy-sealed ceramic lid.



FEATURES

- GaN on SiC HEMT Technology
- Output Power >250 W
- Pre-matched Input Impedance
- High Efficiency 60% typical
- 100% RF Tested Under Link 16 pulse conditions
- RoHS and REACH Compliant



- Link 16 applications
- TACAN/DME Systems

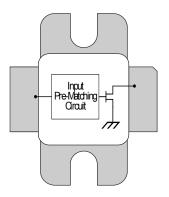


Table 1. Absolute Maximum Ratings (Not Simultaneous)

Parameter	Symbol	Value	Units	Test Conditions
DC Drain-Source Voltage	V _{DS}	160	V	25 °C
DC Gate-Source Voltage	V_{GS}	-8 to +1	V	25 °C
DC Drain Current	I _D	24	А	25 °C
DC Gate Current	I _G	24	mA	25 °C
RF Input Power	P _{REIN}	5.5	W	25 °C
Operating Channel Temperature	Т _{сн}	-55 to +225	°C	
Storage Temperature	T _{STG}	-55 to +150	°C	
Soldering Temperature	T _{SOLDER}	260 for 60s	°C	

Note: Operation outside the limits given in this table may cause permanent damage to the transistor

Table 2.DC Electrical Characteristics (Case temperature = 25 °C unless otherwise stated)

Parameter	Symbol	Min	Тур	Max	Units	Test Conditions
Gate Pinch-Off Voltage	V _P	-5			V	$V_{DS} = 50V, I_{DS} = 1mA$
Quiescent Gate Voltage	V _Q		-2.5		V	V _{DS} = 50V, I _{DS} = 100mA



Table 3. RF Electrical Characteristics (Case temperature = 30 °C unless otherwise stated)

Parameter	Symbol	Min	Тур	Max	Units	Test Conditions
RF Output Power	P _{out, RF}	250	320	500	W	
Gain	G	17	18	20	dB	P _{IN} = 5W f = 960, 1090, 1220 MHz
Drain Efficiency	η	50	60	85	%	$V_{DS}=50V$, $I_{DS}=100$ mA Link 16 pulse conditions (444 x [7 μ s on, 6 μ s off], LTDC = 22.7%
Input Return Loss	IRL	7	12	18	dB	
Pulse Droop	D	-0.5	-0.2	+0.2	dB	
Load Mismatch Stability	VSWR-S	2:1				P _{OUT} = 250W f = 960, 1090, 1220 MHz
VSWR Withstand	VSWR-LMT	3:1				V _{DS} = 50V, I _{DS} = 100mA Link 16 pulse conditions (444 x [7µs on, 6µs off], LTDC = 22.7%

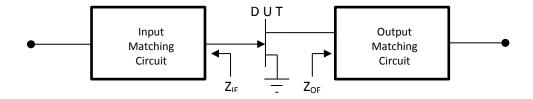
Note: Consult Integra Technologies Application Note 001 for information on how RF output power and pulse droop are measured for the ELM and Link 16 pulse trains.

Table 4. Thermal Resistance (Case temperature = 85 °C unless otherwise stated)

Parameter	Symbol	Тур	Units	Test Conditions
Peak Thermal Resistance, Channel to Case	R _{TH}	0.4	°C/W	$P_{DISS}=213~W$ Link 16 pulse conditions (444 x [7μs on, 6μs off], LTDC = 22.7% $V_{DS}=50V$

Table 5. Test Fixture Source & Load Impedances (Case temperature = 25 °C unless otherwise stated)

Frequency (MHz)	Z _{IF}	Z _{of}	Units	Test Conditions
960	2.6 - j 3.9	3.8 + j 0.1	Ω	P _{OUT} = 250W
1090	2.5 - j 3.4	3.5 - j 0.2	Ω	Link 16 pulse conditions (444 x [7 μ s on, 6 μ s off], LTDC = 22.7% $V_{ps} = 50V, I_{ps} = 20mA$
1215	2.5 - j 2.9	3.8 - j 0.4	Ω	





TYPICAL PERFORMANCE

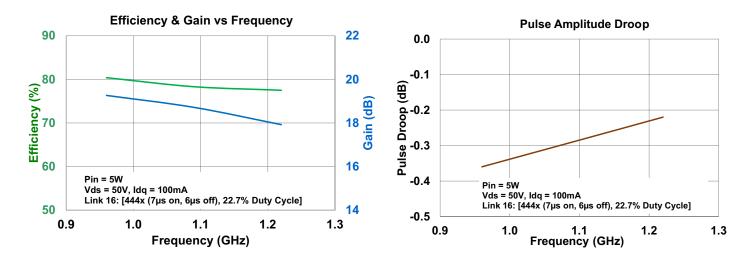


Figure 2

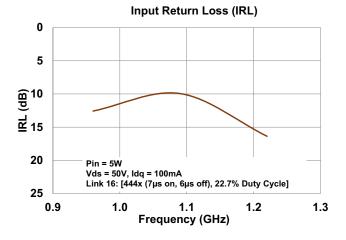
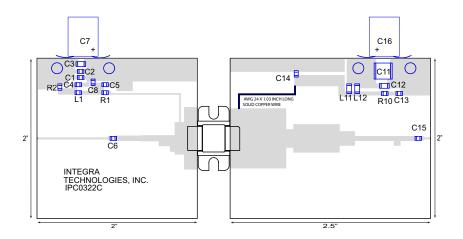


Figure 3



TEST FIXTURE

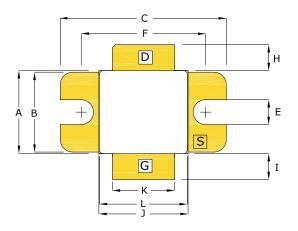


Bill of Materials for IGN0912L250M Test Fixture

Designator	Description
C1, C4, C13	CAP 0.1μF, 0805, 50V
C2	CAP 33pF, 0805, 50V
C3, C12	CAP Electrolytic 1μF, 1206
C5, C6, C14, C15	CAP 3pF, 0805, 50V, Edge Mount
C7, C16	CAP Electrolytic 68μF, 63V
C8	CAP 1000F, 0805, 50V, X7R
L1	IND FB 120 OHM, 5A, 0805
L11, L12	IND 120nH, 0603
L11	IND FB 120 OHM, 5A, 0805
R1, R10	RES 15 OHM, 0805
R2	RES 200 OHM, 0805
PC Board Type	ROGERS RT6010, 25mil, 1/1oz. Copper



PACKAGE PL44C1

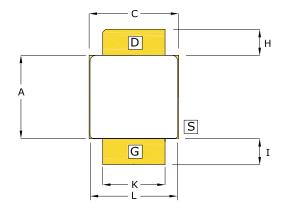


	INCHE:	INCHES		1ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.395	0.405	10.03	10.29
В	0.380	0.390	9.65	9.91
С	0.795	0.805	20.19	20.45
E	0.115	0.125	2.92	3.18
F	0.595	0.605	15.11	15.37
Н	0.110	0.140	2.79	3.56
I	0.110	0.140	2.79	3.56
J	0.425	0.435	10.80	11.05
K	0.295	0.305	7.49	7.75
L	0.420	0.428	10.67	10.87
М	0.035	0.045	0.89	1.14
N	0.004	0.007	0.10	0.18
	0.053	0.067	1.35	1.70
Р	0.143	0.179	3.63	4.55



PIN SCHEDULE
D DRAIN
S SOURCE
G GATE

BOLT-DOWN FLANGE OPTION IGN0912L250M



	INCHE:	2	MILLIM	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.393	0.408	9.97	10.35
В				
С	0.423	0.438	10.73	11.11
E				
F				
Н	0.110	0.140	2.79	3.56
I	0.110	0.140	2.79	3.56
J				
K	0.295	0.305	7.49	7.75
L	0.420	0.428	10.67	10.87
М	0.035	0.045	0.89	1.14
N	0.004	0.007	0.10	0.18
	0.053	0.067	1.35	1.70
Р	0.143	0.179	3.63	4.55



PIN SCHEDULE	
D DRAIN	
S SOURCE	
G GATE	Ξ

EARLESS FLANGE OPTION IGN0912L250MS



ESD & MSL Rating

Parameter	Rating	Standard
ESD Human Body Model (HBM)	TBD	ESDA/JEDEC JS-001-2012
ESD Charged Device Model (CDM)	TBD	JEDEC JESD22-C101F
Moisture Sensitivty Level (MSL)	Unlimited Shelf Life	IPC/JEDEC J-STD-020

RoHS Compliance

Integra Technologies, Inc declares that its GaN and LDMOS Transistor Products comply with EU Directive 2011/65/EU on the restriction of the use of certain hazardous substances in electrical and electronic equipment (RoHS2), as adopted by EU member states on January 2, 2013 and amended on March 31, 2015 by EU Directive 2015/863/EU.

REACH Compliance

Integra Technologies supports EU Regulation number 1907/2006 concerning the Registration, Evaluation, Authorization, and Restriction of Chemicals (REACH) as these apply to Integra semiconductor products, development tools, and shipping packaging.

In support of the REACH regulation, Integra will:

- •Inform customers and recipients of Integra product if they contain any substances that are of very high concern (SVHC) per the European Chemical Agency (ECHA) website.
- •Notify ECHA if any Integra product that contains any SVHCs which exceed guidelines for REACH chemicals by weight per part number and for total content weight per year for all products produced in or imported to the European market.
- •Cease shipments of product containing REACH Annex XIV substances until authorization has been obtained.
- Cease shipment of product containing REACH Annex XVII chemicals when restrictions apply.

Integra has evaluated its materials, BOMs, and product specifications and product and has determined that this transistor conforms to all REACH and SVHC regulations and guidelines. Integra has implemented actions and control programs that will assure continued compliance.

Disclaimer

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DEFINITIONS:

DATA SHEET STATUS

Advanced Specification - This data sheet contains Advanced specifications.

Preliminary Specification - This data sheet contains specifications based on preliminary measurements and data.

Final Specification - This data sheet contains final product specifications.

MAXIMUM RATINGS Stress above one or more of the maximum ratings may cause permanent damage to the device. These are maximum ratings only operation of the device at these or at any other conditions above those given in the characteristics sections of the specification is not implied. Exposure to maximum values for extended periods of time may affect device reliability.

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